Appl. No.: 10/722,460 PRELIMINARY AMENDMENT

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## AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions, and listings, of claims in the application.

# Listing of claims:

1. (Currently Amended) A siloxane-based resin prepared by hydrolyzing and condensing a silane-based monomer having the structure of Formula 1, and at least one monomer selected from the group consisting of compounds of Formulas 2 to 4, in an organic solvent in the presence of an acid or alkaline catalyst and water:

### Formula 1

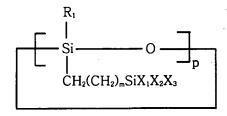
Si[(CH<sub>2</sub>)<sub>k</sub>SiY<sub>1</sub>Y<sub>2</sub>Y<sub>3</sub>]<sub>4</sub>

wherein,

k is an integer of 1-10; and

 $Y_1$ ,  $Y_2$  and  $Y_3$  are independently a  $C_1$ - $C_3$  alkyl group, a  $C_1$ - $C_{10}$  alkoxy group, or a halogen atom, provided that at least one of them is hydrolyzable,

# Formula 2



wherein,

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 $R_1$  is a  $C_1$ - $C_3$  alkyl group, or a  $C_6$ - $C_{15}$  aryl group;

 $X_1$ ,  $X_2$  and  $X_3$  are independently a hydrogen atom, a  $C_1$ - $C_3$  alkyl group, a  $C_1$ - $C_{10}$  alkoxy group, or a halogen atom, provided that at least one of them is hydrolyzable;

m is an integer of 0-10; and

p is an integer of 3-8,

### Formula 3

$$X_{1} - \begin{cases} R_{2} \\ I \\ S_{1} - O \\ I \\ Y_{1} \end{cases} = \begin{cases} R_{2} \\ I \\ S_{1} - O \\ I \\ R_{2} \end{cases} = \begin{cases} R_{2} \\ I \\ S_{1} - X_{1} \\ I \\ Y_{1} \end{cases}$$

wherein,

 $R_2$  is a  $C_1$ - $C_3$  alkyl group, or a  $C_6$ - $C_{15}$  aryl group;

X4 is a hydrogen atom, or a C1-C10 alkoxy group;

 $Y_1$  is a hydrogen atom, a  $C_1$ - $C_3$  alkyl group or a  $C_1$ - $C_{10}$  alkoxy group; and

n is an integer of 0-10, and

## Formula 4

 $R_3Si(X_5X_6X_7)_3$   $R_3SiX_5X_6X_7$ 

wherein,

 $R_3$  is a  $C_1$ - $C_3$  alkyl group, or a  $C_6$ - $C_{15}$  aryl group;

 $X_5,\,X_6$  and  $X_7$  are independently a hydrogen atom, a  $C_1\text{-}C_3$  alkyl group,

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a C<sub>1</sub>-C<sub>10</sub> alkoxy group, or a halogen atom, provided that at least one of them is

hydrolyzable.

2. (Original) The siloxane-based resin according to claim 1, wherein the

molar ratio of the monomer of Formula 1 to the monomer selected from the

group consisting of compounds of Formulas 2 to 4 is 1:99 to 99:1.

3. (Original) The siloxane-based resin according to claim 1, wherein the

catalyst is selected from the group consisting of hydrochloric acid, nitric acid,

benzene sulfonic acid, oxalic acid, formic acid, potassium hydroxide, sodium

hydroxide, triethylamine, sodium bicarbonate, pyridine, and mixtures thereof.

4. (Original) The siloxane-based resin according to claim 1, wherein the

molar ratio of the monomer to the catalyst is 1:0.000001 to 1:10.

5. (Original) The siloxane-based resin according to claim 1, wherein the

molar ratio of the monomer to water is 1:1 to 1:1000.

6. (Original) The siloxane-based resin according to claim 1, wherein the

hydrolysis and condensation reactions are performed at 0-200°C for 0.1-100

hours.

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7. (Original) The siloxane-based resin according to claim 1, wherein the

organic solvent is selected from the group consisting of an aliphatic

hydrocarbon solvent, an aromatic hydrocarbon solvent, a ketone-based

solvent, an ether-based solvent, an acetate-based solvent, an alcohol-based

solvent, an amide-based solvent, a silicon-based solvent, and mixtures

thereof.

8. (Original) The siloxane-based resin according to claim 1, wherein the

weight average molecular weight of the resin is 3,000 to 300,000.

9. (Original) A method of preparing a semiconductor interlayer

insulating film which comprises:

providing a liquid coating composition by dissolving the siloxane-based

resin according to claim 1 in an organic solvent;

coating a silicon wafer with the liquid coating composition to form a

coating film; and

heat-curing the coating film.

10. (Original) The method according to claim 9, wherein the siloxane-

based resin is mixed with a porogen so that the weight ratio of the resin to the

porogen is 99:1-30:70.

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11. (Original) The method according to claim 10, wherein the porogen

is selected from the group consisting of cyclodextrin, polycaprolactone and

derivatives thereof.

12. (Original) The method according to claim 9, wherein the organic

solvent is selected from the group consisting of an aliphatic hydrocarbon

solvent, an aromatic hydrocarbon solvent, a ketone-based solvent, an ether-

based solvent, an acetate-based solvent, an alcohol-based solvent, an amide-

based solvent, a silicon-based solvent, and mixture thereof.

13. (Original) The method according to claim 9, wherein the weight

ratio of solid component containing the siloxane-based resin and the porogen

is 5-70 wt% based on the total weight of the composition.

14. (Original) The method according to claim 9, wherein the liquid

coating composition is applied to the silicon wafer through spin coating.

15. (Original) The method according to claim 9, wherein the heat

curing is performed at a temperature of 150-600°C for 1-150 min.

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16. (Original) A semiconductor interlayer insulating film, comprising

the siloxane-based resin of claim 1.

17. (Original) The semiconductor interlayer insulating film according to

claim 16, wherein micropores are formed throughout the film by the use of a

porogen.

18. (Original) The semiconductor interlayer insulating film according to

claim 17, wherein the porogen is selected from the group consisting of

cyclodextrin, polycaprolactone and derivatives thereof.

CLAIMS 19-20 (CANCELLED)